



# PSMN3R9-60PS

N-channel 60 V, 3.9 mΩ standard level MOSFET in SOT78

1 February 2013

Product data sheet

## 1. General description

Standard level N-channel MOSFET in SOT78 using TrenchMOS technology. Product design and manufacture has been optimized for use in battery operated power tools.

## 2. Features and benefits

- High efficiency due to low switching & conduction losses
- Robust construction for demanding applications
- Standard level gate

## 3. Applications

- Battery-powered tools
- Load switching
- Motor control
- Uninterruptible power supplies

## 4. Quick reference data

Table 1. Quick reference data

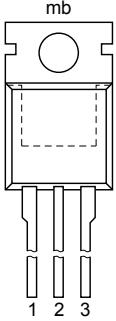
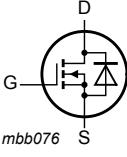
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \geq 25 \text{ }^\circ\text{C}; T_j \leq 175 \text{ }^\circ\text{C}$		-	-	60	V
$I_D$	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 1</a>	[1]	-	-	130	A
$P_{tot}$	total power dissipation	$T_{mb} = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 2</a>		-	-	263	W
<b>Static characteristics</b>							
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a>		-	2.94	3.9	mΩ
<b>Dynamic characteristics</b>							
$Q_{G(tot)}$	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 10 \text{ V}$ ;		-	103	-	nC
$Q_{GD}$	gate-drain charge	<a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a>		-	33	-	nC
<b>Avalanche ruggedness</b>							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 130 \text{ A}; V_{sup} \leq 60 \text{ V}; R_{GS} = 50 \Omega$ ; $V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ }^\circ\text{C}$ ; unclamped; <a href="#">Fig. 3</a>		-	-	283	mJ

[1] Continuous current is limited by package.

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## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
mb	D	mounting base; connected to drain	 <b>TO-220AB (SOT78)</b>	

## 6. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description		
PSMN3R9-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB		SOT78

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN3R9-60PS	PSMN3R9-60PS

## 8. Limiting values

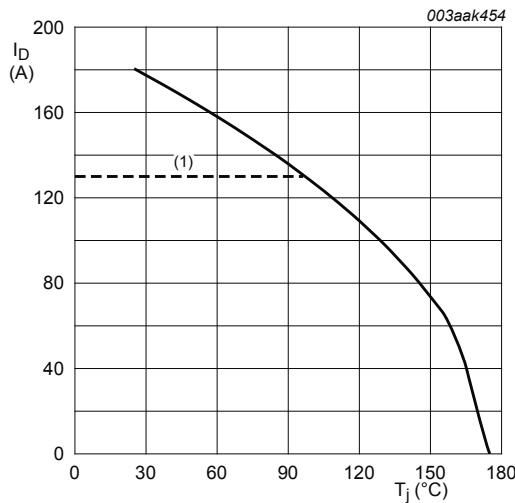
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$T_j \geq 25^\circ\text{C}$ ; $T_j \leq 175^\circ\text{C}$	-	60	V
$V_{DGR}$	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$	-	60	V
$V_{GS}$	gate-source voltage		-20	20	V
$I_D$	drain current	$T_{mb} = 25^\circ\text{C}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 1</a>	[1]	130	A
		$T_{mb} = 100^\circ\text{C}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 1</a>	-	127	A
$I_{DM}$	peak drain current	$T_{mb} = 25^\circ\text{C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; <a href="#">Fig. 4</a>	-	705	A

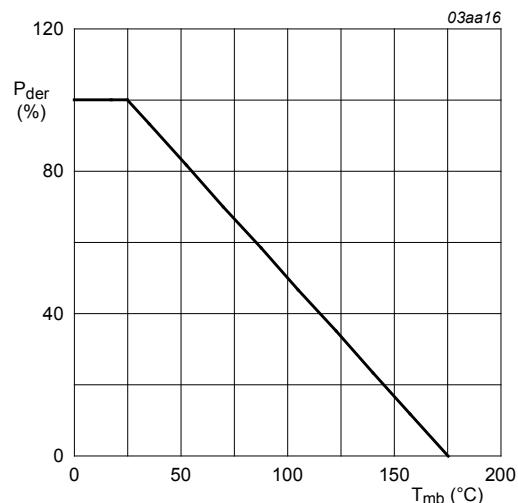
Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <a href="#">Fig. 2</a>	-	263	W
T <sub>stg</sub>	storage temperature		-55	175	°C
T <sub>j</sub>	junction temperature		-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature		-	260	°C
<b>Source-drain diode</b>					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	130 A
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C	-	705	A
<b>Avalanche ruggedness</b>					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	I <sub>D</sub> = 130 A; V <sub>sup</sub> ≤ 60 V; R <sub>GS</sub> = 50 Ω; V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C; unclamped; <a href="#">Fig. 3</a>	-	283	mJ

[1] Continuous current is limited by package.



**Fig. 1. Continuous drain current as a function of mounting base temperature**

$V_{GS} \geq 10 \text{ V}$   
(1) Capped at 130 A due to package.



**Fig. 2. Normalized total power dissipation as a function of mounting base temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100 \%$$

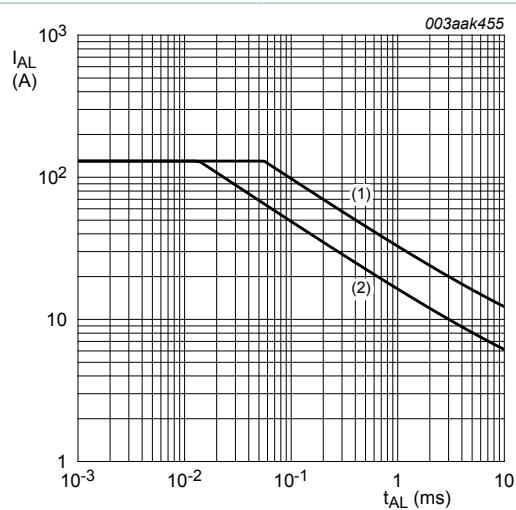


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

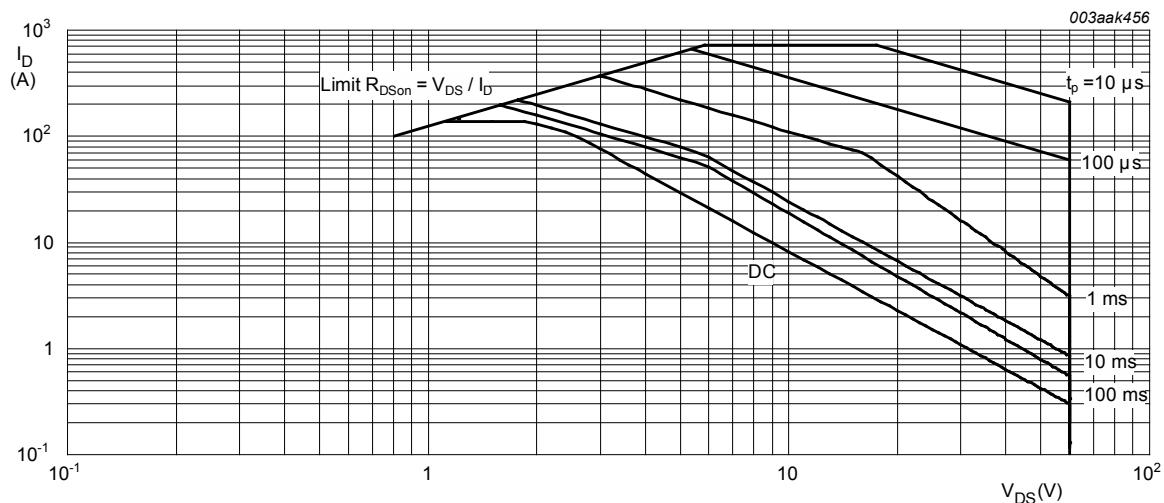
(1)  $T_J (int) = 25^\circ C$ ; (2)  $T_J (int) = 100^\circ C$ 

Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^\circ C$ ;  $I_{DM}$  is a single pulse

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 5</a>		-	0.49	0.57	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in still air		-	60	-	K/W

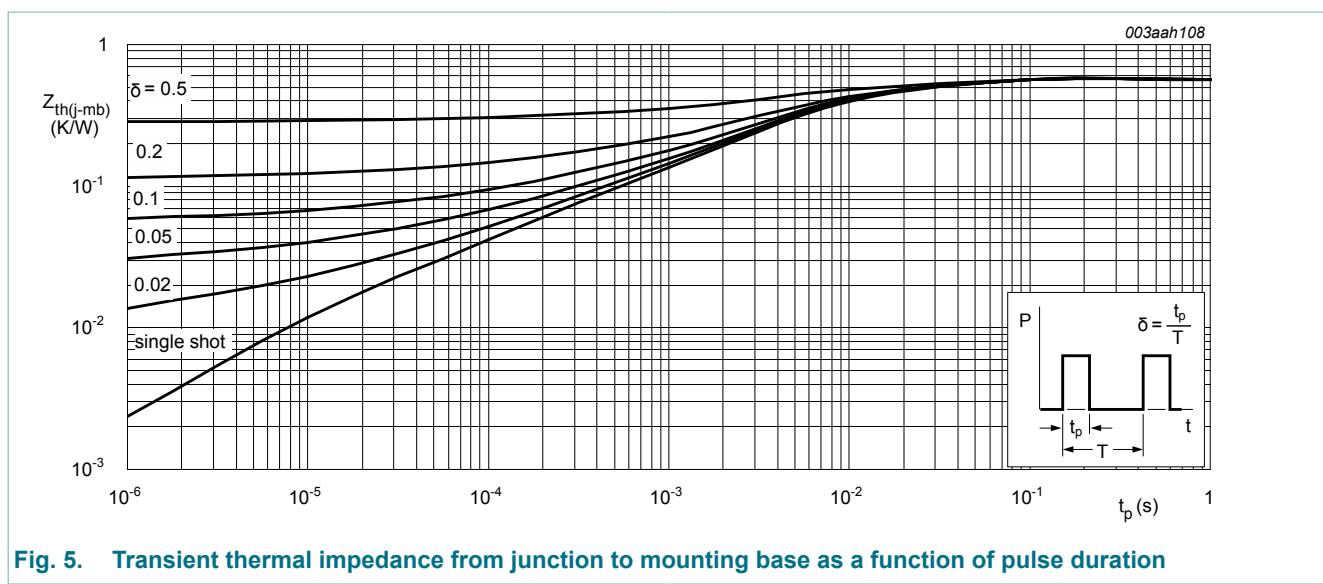


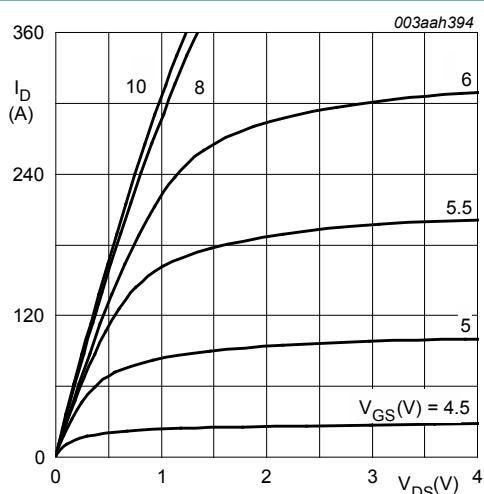
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

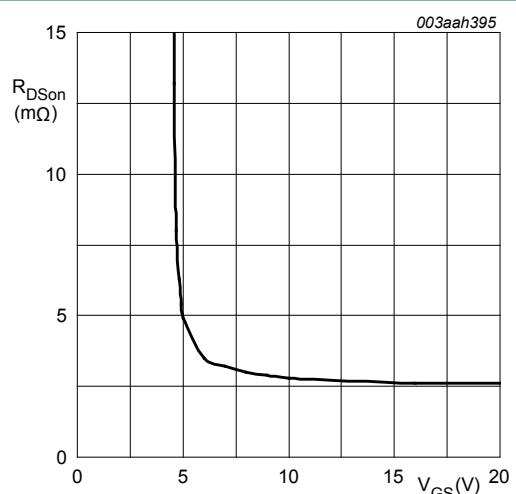
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Static characteristics</b>							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$		60	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$		54	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C;$ <a href="#">Fig. 9</a> ; <a href="#">Fig. 10</a>		2.4	3	4	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C;$ <a href="#">Fig. 9</a>		1	-	-	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C;$ <a href="#">Fig. 9</a>		-	-	4.5	V
$I_{DSS}$	drain leakage current	$V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175^\circ C$		-	-	500	$\mu A$
		$V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25^\circ C$		-	0.07	1	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	2	100	nA
		$V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	2	100	nA
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C;$ <a href="#">Fig. 11</a>		-	2.94	3.9	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C;$ <a href="#">Fig. 11</a> ; <a href="#">Fig. 12</a>		-	-	8.5	$m\Omega$
$R_G$	gate resistance	$f = 1 MHz$		0.35	0.7	1.4	$\Omega$
<b>Dynamic characteristics</b>							
$Q_{G(\text{tot})}$	total gate charge	$I_D = 25 A; V_{DS} = 48 V; V_{GS} = 10 V;$ <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a>		-	103	-	nC
$Q_{GS}$	gate-source charge			-	25.1	-	nC

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$Q_{GD}$	gate-drain charge			-	33	-	nC
$C_{iss}$	input capacitance	$V_{GS} = 0 \text{ V}$ ; $V_{DS} = 25 \text{ V}$ ; $f = 1 \text{ MHz}$ ;		-	5600	-	pF
$C_{oss}$	output capacitance	$T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 15</a>		-	740	-	pF
$C_{rss}$	reverse transfer capacitance			-	460	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 45 \text{ V}$ ; $R_L = 1.8 \Omega$ ; $V_{GS} = 10 \text{ V}$ ;		-	25.3	-	ns
$t_r$	rise time	$R_{G(ext)} = 5 \Omega$		-	41.4	-	ns
$t_{d(off)}$	turn-off delay time			-	62.7	-	ns
$t_f$	fall time			-	45	-	ns
<b>Source-drain diode</b>							
$V_{SD}$	source-drain voltage	$I_S = 25 \text{ A}$ ; $V_{GS} = 0 \text{ V}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 16</a>		-	0.8	1.2	V
$t_{rr}$	reverse recovery time	$I_S = 20 \text{ A}$ ; $dI_S/dt = -100 \text{ A}/\mu\text{s}$ ; $V_{GS} = 0 \text{ V}$ ;		-	39	-	ns
$Q_r$	recovered charge	$V_{DS} = 25 \text{ V}$		-	51	-	nC



**Fig. 6.** Output characteristics; drain current as a function of drain-source voltage; typical values



**Fig. 7.** Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^\circ C; \quad I_D = 25A$$

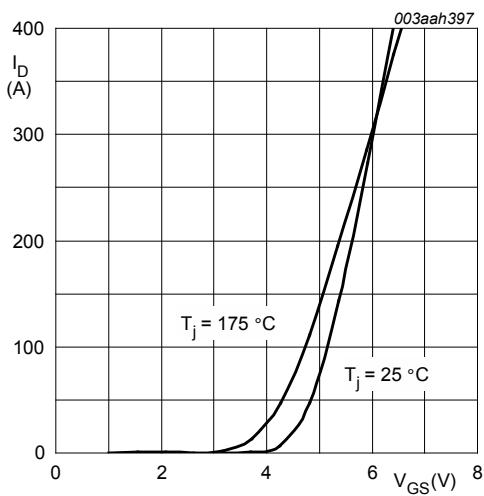


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

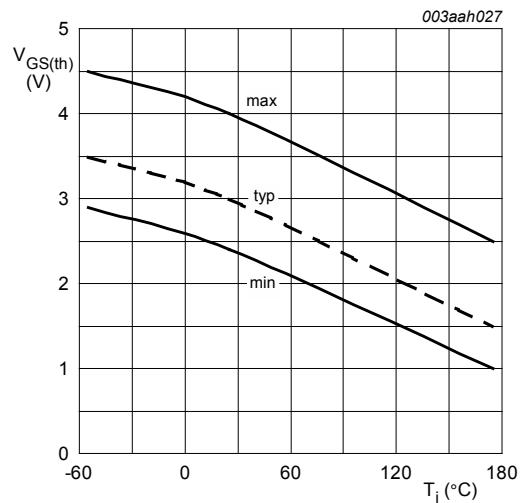


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$I_D = 1$  mA;  $V_{DS} = V_{GS}$

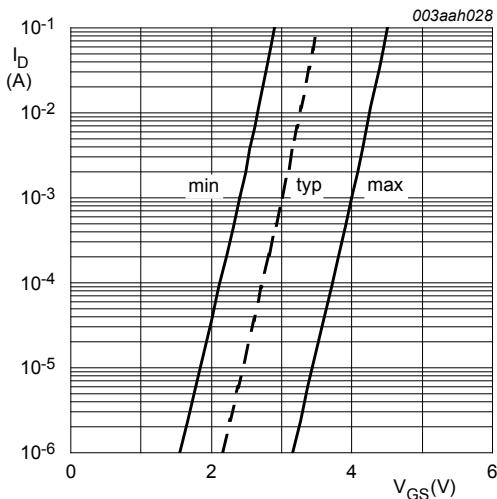
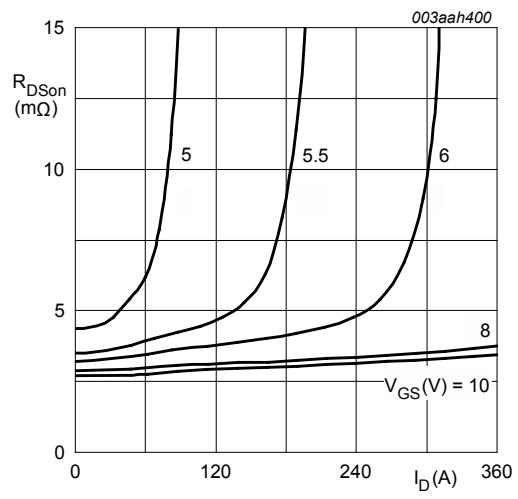


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25$  °C;  $V_{DS} = 5V$



$T_j = 25$  °C;  $t_p = 300$  μs

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

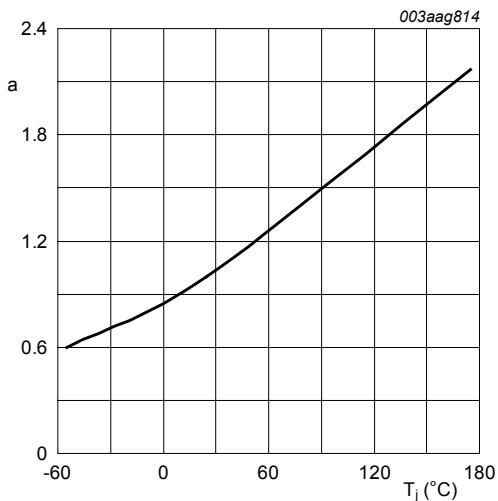


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25\text{ }^{\circ}\text{C})}}$$

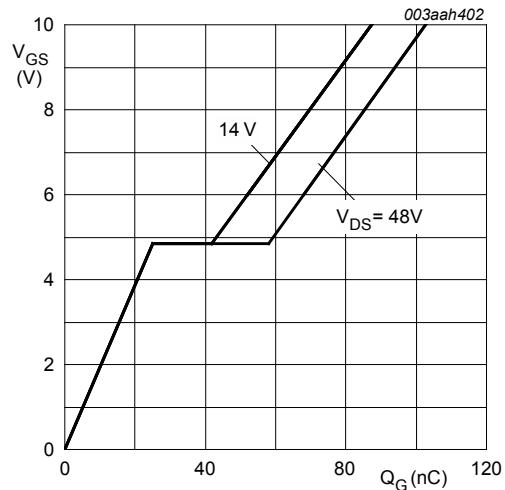


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}\text{C}; I_D = 25\text{A}$$

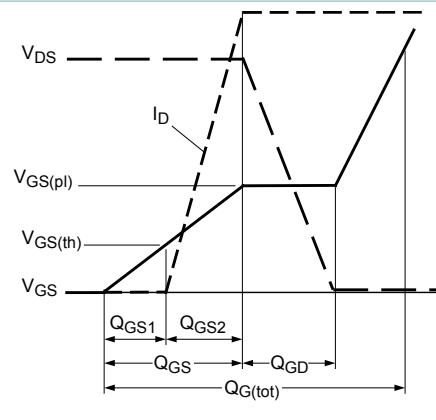


Fig. 13. Gate charge waveform definitions

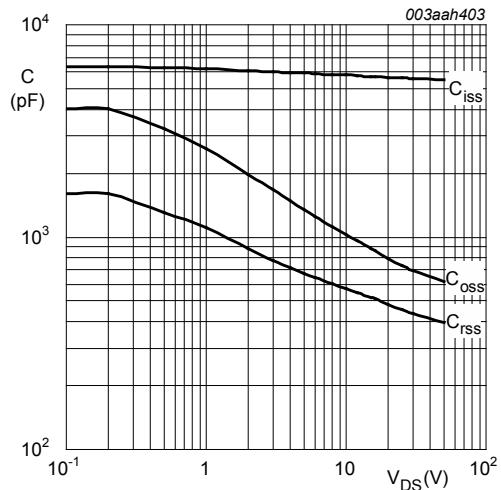


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$$

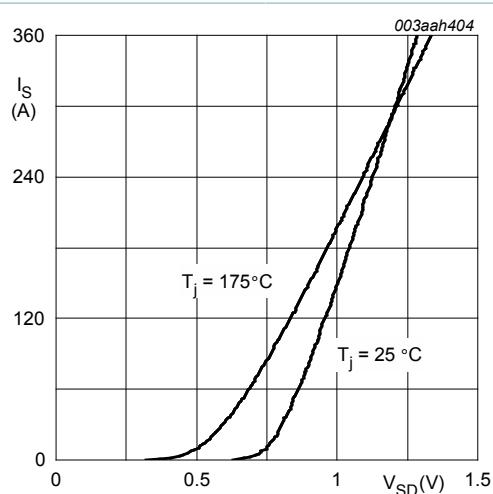
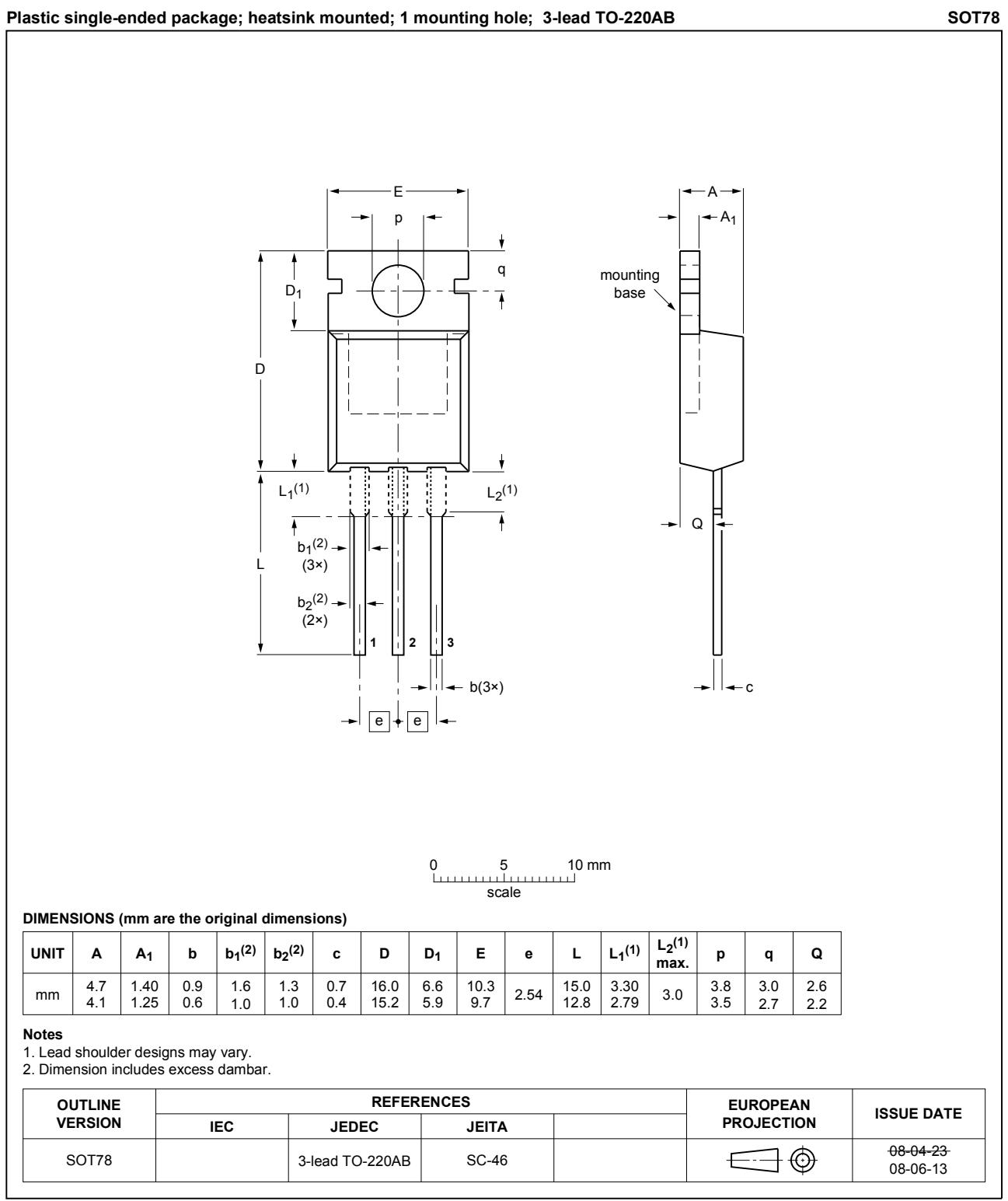


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$V_{GS} = 0V$

## 11. Package outline



## 12. Legal information

### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## 13. Contents

1	General description .....	1
2	Features and benefits .....	1
3	Applications .....	1
4	Quick reference data .....	1
5	Pinning information .....	2
6	Ordering information .....	2
7	Marking .....	2
8	Limiting values .....	2
9	Thermal characteristics .....	4
10	Characteristics .....	5
11	Package outline .....	10
12	Legal information .....	11
12.1	Data sheet status .....	11
12.2	Definitions .....	11
12.3	Disclaimers .....	11
12.4	Trademarks .....	12

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